

Dual, Low Power Operational Amplifiers

Utilizing the circuit designs perfected for the quad operational amplifiers, these dual operational amplifiers feature: 1) low power drain, 2) a common mode input voltage range extending to ground/VEE, and 3) Single Supply or Split Supply operation.

These amplifiers have several distinct advantages over standard operational amplifier types in single supply applications. They can operate at supply voltages as low as 3.0 V or as high as 36 V with quiescent currents about one–fifth of those associated with the MC1741C (on a per amplifier basis). The common mode input range includes the negative supply, thereby eliminating the necessity for external biasing components in many applications. The output voltage range also includes the negative power supply voltage.

- Short Circuit Protected Outputs
- True Differential Input Stage
- Single Supply Operation: 3.0 V to 36 V
- Low Input Bias Currents
- Internally Compensated
- Common Mode Range Extends to Negative Supply
- Class AB Output Stage for Minimum Crossover Distortion
- Single and Split Supply Operations Available
- Similar Performance to the Popular MC1458

MC3458 MC3358

DUAL DIFFERENTIAL INPUT OPERATIONAL AMPLIFIERS

SEMICONDUCTOR TECHNICAL DATA



P1 SUFFIX PLASTIC PACKAGE CASE 626



D SUFFIXPLASTIC PACKAGE
CASE 751
(SO-8)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltages			Vdc
Single Supply	VCC	36	
Split Supplies	V _{CC} , V _{EE}	±18	
Input Differential Voltage Range (1)	V _{IDR}	±30	Vdc
Input Common Mode Voltage Range (2)	VICR	±15	Vdc
Junction Temperature	TJ	150	°C
Storage Temperature Range	T _{stg}	-55 to +125	°C
Operating Ambient Temperature Range	TA		°C
MC3458		0 to +70	
MC3358		-40 to +85	

NOTES: 1. Split Power Supplies.

2. For supply voltages less than ± 18 V, the absolute maximum input voltage is equal to the supply voltage.

ORDERING INFORMATION

Device	Operating Temperature Range	Package
MC3358P1	$T_A = -40^{\circ} \text{ to } +85^{\circ}\text{C}$	Plastic DIP
MC3458D	T _A = 0° to +70°C	SO-8
MC3458P1	1A = 0 10 +70 C	Plastic DIP

 $\textbf{ELECTRICAL CHARACTERISTICS} \ \ (\text{For MC3458, V}_{CC} = +15 \text{ V}, \text{ V}_{EE} = -15 \text{ V}, \text{ T}_{A} = 25^{\circ}\text{C}, \text{ unless otherwise noted.})$ (For MC3358, V_{CC} = +14 V, V_{EE} = Gnd, T_A = 25°C, unless otherwise noted.)

		MC3458		MC3358				
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage TA = Thigh to Tlow (Note 1)	V _{IO}	- -	2.0 -	10 12	_ _	2.0	8.0 10	mV
Input Offset Current TA = Thigh to Tlow	I _{IO}	_ _	30 -	50 200	- -	30 -	75 250	nA
Large Signal Open Loop Voltage Gain $V_O=\pm 10~V,~R_L=2.0~k\Omega,~T_A=T_{high}~to~T_{low}$	AVOL	20 15	200 –	- -	20 15	200 –	_ _	V/mV
Input Bias Current TA = Thigh to Tlow	I _{IB}	_ _	-200 -	-500 -800	_ _	-200 -	-500 -1000	nA
Output Impedance, f = 20 Hz	zO	-	75	_	_	75	-	Ω
Input Impedance, f = 20 Hz	ΖĮ	0.3	1.0	_	0.3	1.0	-	ΜΩ
Output Voltage Range $R_L = 10 \text{ k}\Omega$ $R_L = 2.0 \text{ k}\Omega$ $R_L = 2.0 \text{ k}\Omega, T_A = T_{high} \text{ to } T_{low}$ Input Common Mode Voltage Range	VOR	±12 ±10 ±10	±13.5 ±13 - +13.5 -VEE	- - -	12 10 10 +13 -VEE	12.5 12 - +13.5 -VEE	- - -	V
Common Mode Rejection Ratio, R _S ≤ 10 kΩ	CMR	70	90	_	70	90	_	dB
Power Supply Current ($V_O = 0$) $R_L = \infty$		ļ		3.7		1.6	3.7	-
Individual Output Short Circuit Current (Note 2)	ICC, IEE	-	1.6		-			mA
	ISC	±10	±20	±45	±10	±30	±45	mA
Positive Power Supply Rejection Ratio	PSRR+	-	30	150	_	30	150	μV/V
Negative Power Supply Rejection Ratio Average Temperature Coefficient of Input Offset Current, T _A = T _{high} to T _{low}	PSRR- ΔΙ _{ΙΟ} /ΔΤ	-	30 50	150 –	_	50	_	μV/V pA/°C
Average Temperature Coefficient of Input Offset Current, T _A = T _{high} to T _{low}	ΔV _{IO} /ΔΤ	-	10	_	-	10	-	μV/°C
Power Bandwidth $A_V = 1$, $R_L = 2.0 \text{ k}\Omega$, $V_O = 20 \text{ V}_{pp}$, THD = 5%	BWp	-	9.0	-	-	9.0	_	kHz
Small Signal Bandwidth $A_V = 1, R_L = 10 k\Omega, V_O = 50 mV$	BW	_	1.0	-	-	1.0	_	MHz
Slew Rate $A_V = 1$, $V_I = -10 \text{ V}$ to +10 V	SR	-	0.6	_	-	0.6	_	V/µs
Rise Time $A_V = 1$, $R_L = 10 \text{ k}\Omega$, $V_O = 50 \text{ mV}$	tTLH	-	0.35	_	_	0.35	-	μs
Fall Time $A_V = 1$, $R_L = 10 \text{ k}\Omega$, $V_O = 50 \text{ mV}$	tTHL	-	0.35	_	_	0.35	_	μs
Overshoot $A_V = 1$, $R_L = 10 \text{ k}\Omega$, $V_O = 50 \text{ mV}$	os	-	20	_	-	20	_	%
Phase Margin $A_V=1,R_L=2.0\;k\Omega,C_L=200\;pF$	φm	_	60	-	-	60	_	Degrees
Crossover Distortion $(V_{in} = 30 \text{ mV}_{pp}, V_{out} = 2.0 \text{ V}_{pp}, f = 10 \text{ kHz})$	-	-	1.0	-	_	1.0	-	%

NOTES: 1. T_{high} = 70°C for MC3458, 85°C for MC3358 T_{low} = 0°C for MC3458, -40°C for MC3358 2. Not to exceed maximum package power dissipation.

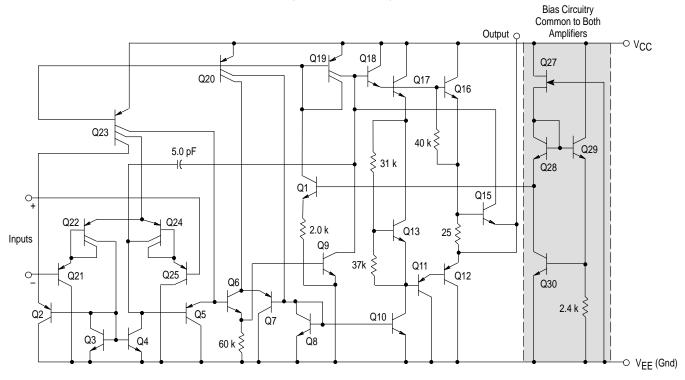
ELECTRICAL CHARACTERISTICS ($V_{CC} = 5.0 \text{ V}$, $V_{EE} = Gnd$, $T_A = 25^{\circ}C$, unless otherwise noted.)

			MC3458			MC3358	· ·	
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	_	2.0	5.0	-	2.0	10	mV
Input Offset Current	ΙΙΟ	_	30	50	-	_	75	nA
Input Bias Current	I _{IB}	_	-200	-500	_	_	-500	nA
Large Signal Open Loop Voltage Gain $R_L = 2.0 \text{ k}\Omega$,	A _{VOL}	20	200	-	20	200	-	V/mV
Power Supply Rejection Ratio	PSRR	_	-	150	_	-	150	μV/V
Output Voltage Range (Note 3) $R_L = 10 \text{ k}\Omega$, $V_{CC} = 5.0 \text{ V}$ $R_L = 10 \text{ k}\Omega$, $5.0 \text{ V} \le V_{CC} \le 30 \text{ V}$	VOR	3.3	3.5 V _{CC} -1.7	_ _	3.3 -	3.5 V _{CC} -1.7	_ _	V _{pp}
Power Supply Current	ICC	_	2.5	7.0	_	2.5	4.0	mA
Channel Separation f = 1.0 kHz to 20 kHz (Input Referenced)	CS	_	-120	-	-	-120	-	dB

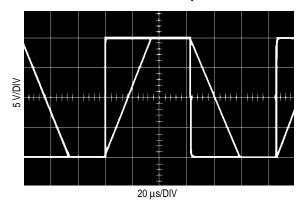
NOTE: 3. Output will swing to ground with a 10 k Ω pull down resistor.

Representative Schematic Diagram

(1/2 of Circuit Shown)



Inverter Pulse Response



CIRCUIT DESCRIPTION

The MC3458/3358 is made using two internally compensated, two-stage operational amplifiers. The first stage of each consists of differential input devices Q24 and Q22 with input buffer transistors Q25 and Q21 and the

differential to single ended converter Q3 and Q4. The first stage performs not only the first stage gain function but also performs the level shifting and transconductance reduction functions. By reducing the transconductance, a smaller compensation capacitor (only 5.0 pF) can be employed, thus saving chip area. The transconductance reduction is accomplished by splitting the collectors of Q24 and Q22. Another feature of this input stage is that the input Common Mode range can include the negative supply or ground, in single supply operation, without saturating either the input devices or the differential to single—ended converter. The second stage consists of a standard current source load amplifier stage.

The output stage is unique because it allows the output to swing to ground in single supply operation and yet does not exhibit any crossover distortion in split supply operation. This is possible because Class AB operation is utilized.

Each amplifier is biased from an internal voltage regulator which has a low temperature coefficient thus giving each amplifier good temperature characteristics as well as excellent power supply rejection.

Figure 1. Sine Wave Response

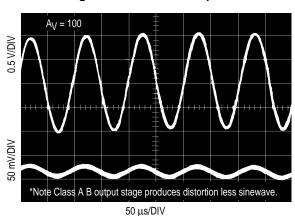


Figure 2. Open Loop Frequency Response

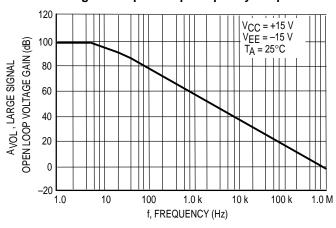


Figure 3. Power Bandwidth

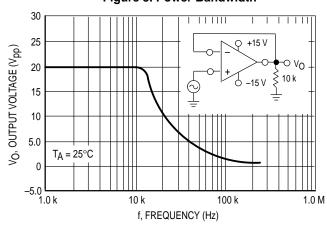


Figure 4. Output Swing versus Supply Voltage

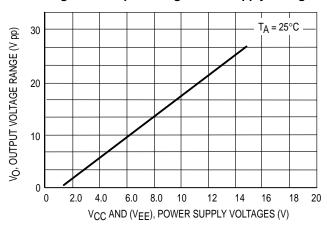


Figure 5. Input Bias Current versus Temperature

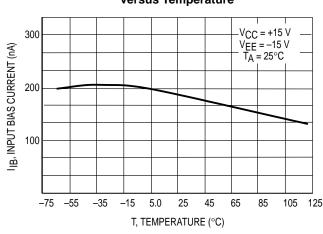


Figure 6. Input Bias Current versus Supply Voltage

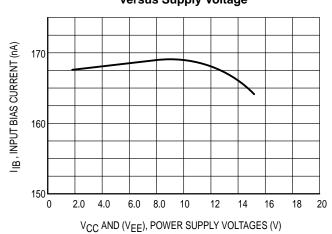


Figure 7. Voltage Reference

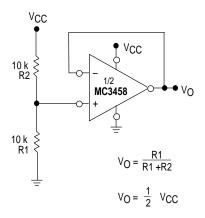


Figure 8. Wien Bridge Oscillator

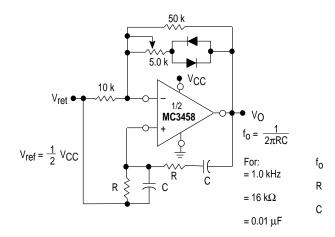


Figure 9. High Impedance Differential Amplifier

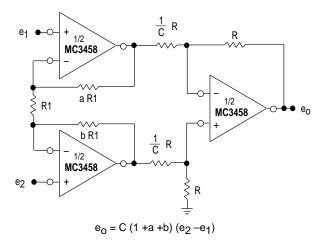


Figure 10. Comparator with

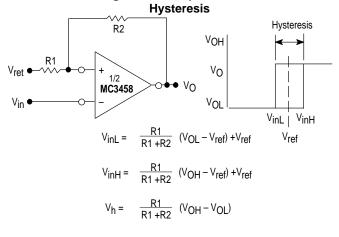


Figure 11. Bi-Quad Filter

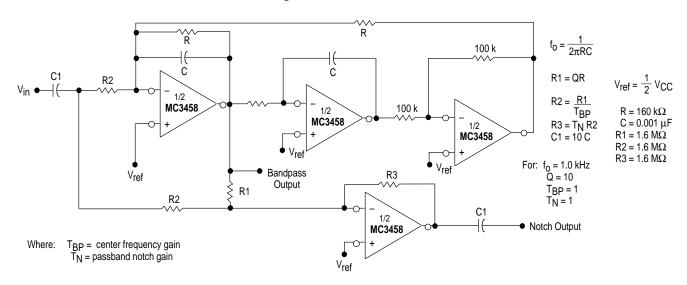


Figure 12. Function Generator

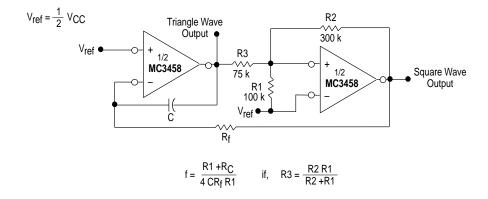
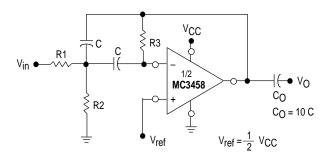


Figure 13. Multiple Feedback Bandpass Filter



Given: f_0 = center frequency $A(f_0)$ = gain at center frequency

Choose value fo, C.

Then: R3 = $\frac{Q}{\pi f_0 C}$ R1 = $\frac{R3}{2 A(f_0)}$ R2 = $\frac{R1 R5}{4Q^2 R1 - R3}$

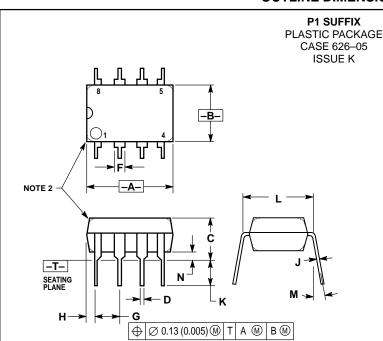
For less than 10% error from operational amplifier $\frac{Q_0 f_0}{RW} < 0.$

where, fo and BW are expressed in Hz.

If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

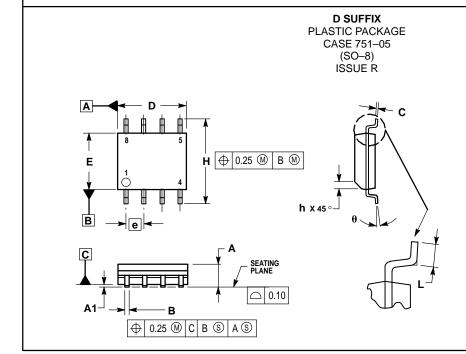
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OUTLINE DIMENSIONS



- NOTES:
 1. DIMENSION L TO CENTER OF LEAD WHEN
- DIMENSION: 10 CENTER OF LEAD WHEN FORMED PARALLEL.
 PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
 DIMENSIONING AND TOLERANCING PER ANSI

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	9.40	10.16	0.370	0.400	
В	6.10	6.60	0.240	0.260	
С	3.94	4.45	0.155	0.175	
D	0.38	0.51	0.015	0.020	
F	1.02	1.78	0.040	0.070	
G	2.54	BSC	0.100 BSC		
Н	0.76	1.27	0.030	0.050	
J	0.20	0.30	0.008	0.012	
K	2.92	3.43	0.115	0.135	
L	7.62	BSC	0.300 BSC		
M		10°		10°	
N	0.76	1.01	0.030	0.040	



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 DIMENSIONS ARE IN MILLIMETERS.

 DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.

- MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
 DIMENSION B DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS
 OF THE B DIMENSION AT MAXIMUM MATERIAL
 CONDITION.

	MILLIMETERS					
DIM	MIN	MAX				
Α	1.35	1.75				
A1	0.10	0.25				
В	0.35	0.49				
С	0.18	0.25				
D	4.80	5.00				
Е	3.80	4.00				
е	1.27	1.27 BSC				
Н	5.80	6.20				
h	0.25	0.50				
L	0.40	1.25				
θ	0°	7°				

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